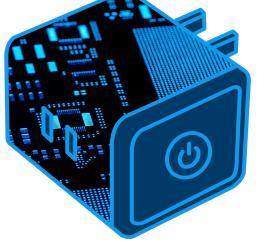
Smart Plug

Solution Proposal by Toshiba



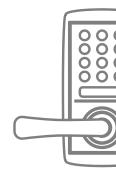






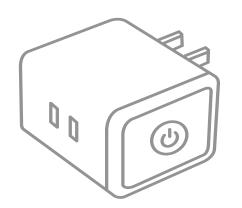




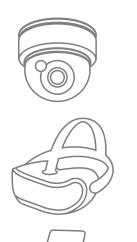








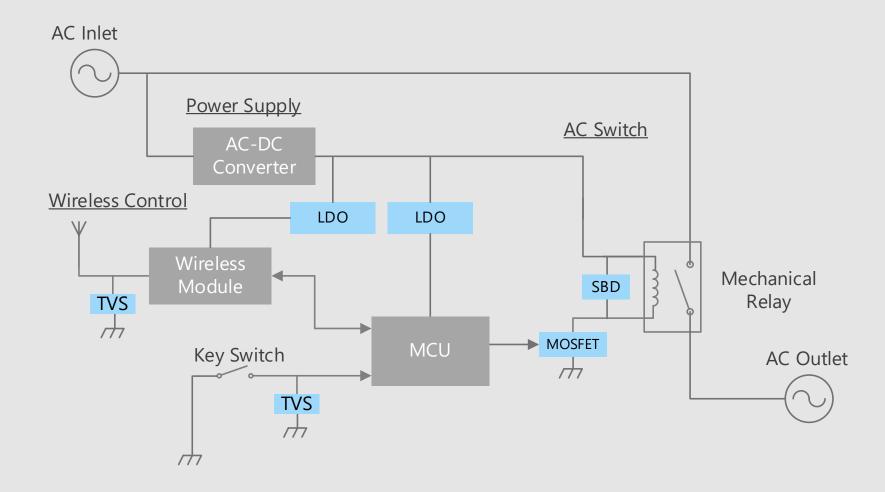
Toshiba Electronic Devices & Storage Corporation provides comprehensive device solutions to customers developing new products by applying its thorough understanding of the systems acquired through the analysis of basic product designs.



Block Diagram

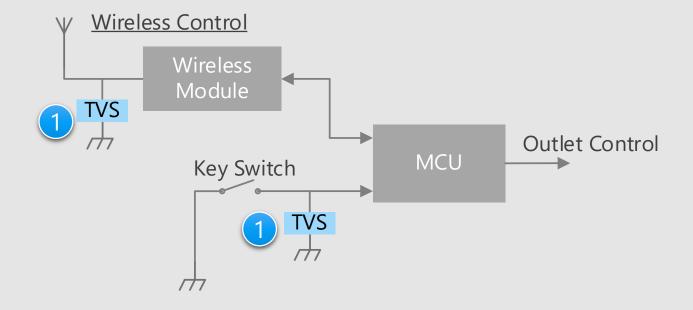
© 2019-2022 Toshiba Electronic Devices & Storage Corporation

Smart Plug Overall block diagram



Smart Plug Detail of wireless and key switch section

Wireless and key switch input circuit



Criteria for device selection

 Since components such as key switches and antennas which may be exposed to the outside environment, ESD protection circuitry may be required.

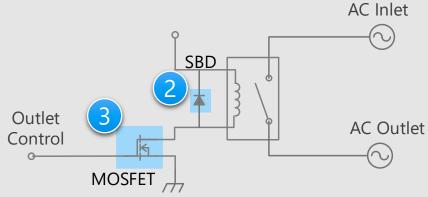
Proposal from Toshiba

 Prevent circuit malfunctions by absorbing electrostatic discharge (ESD) from external terminals
 TVS diode

^{*} Click on the blue circled numbers above to view detailed descriptions.

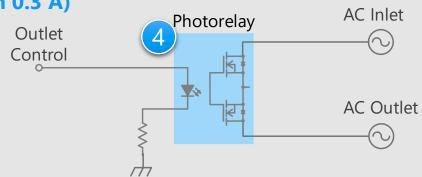
Smart Plug Details of AC switch section (1)

AC switch circuit using mechanical relay



SBD: Schottky barrier diode

AC switch circuit using photorelay (less than 0.3 A)



Criteria for device selection

- Schottky barrier diodes are suitable for freewheeling diodes used in inductive loads such as relays.
- Low power AC switches can be realized using photorelays.

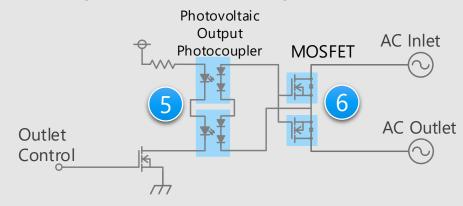
Proposal from Toshiba

- Diodes suitable for freewheeling diodes
 Schottky barrier diode
- Small package and low on-resistance MOSFET
 - Small signal MOSFET
- Designed for high AC isolation voltage Photorelay

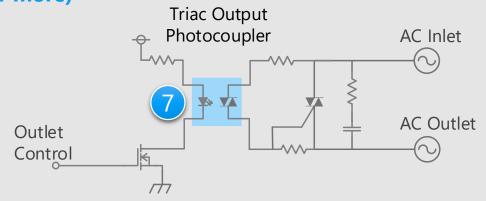
^{*} Click on the blue circled numbers above to view detailed descriptions.

Details of AC switch section (2) Smart Plug

AC switch circuit using photovoltaic output photocouplers and MOSFETs (around 0.3 A to 1 A)



AC switch circuit using triac and triac output photocouplers (1 A or more)



* Click on the blue circled numbers above to view detailed descriptions.

Criteria for device selection

- Isolated AC switch can be realized using a MOSFET driven by a photovoltaic output photocoupler.
- AC switch can be realized using a triac driven by a triac output photocoupler.

Proposal from Toshiba

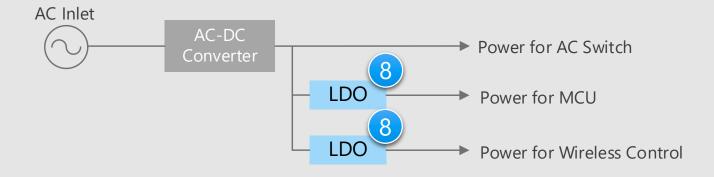
- **Photocoupler for direct MOSFET** driving
 - Photovoltaic output photocoupler
- **Suitable for high efficiency power** switching DTMOSIV Series MOSFET
- **Photocoupler suitable for AC control** Triac output photocoupler
- 6)





Smart Plug Detail of power supply

Power supply circuit



Criteria for device selection

 For the power supply of an IC including an analog circuit such as wireless control, a low noise power supply is required for stable operation of the set.

Proposal from Toshiba

Supply the power with low noise
 Small surface mount LDO regulator

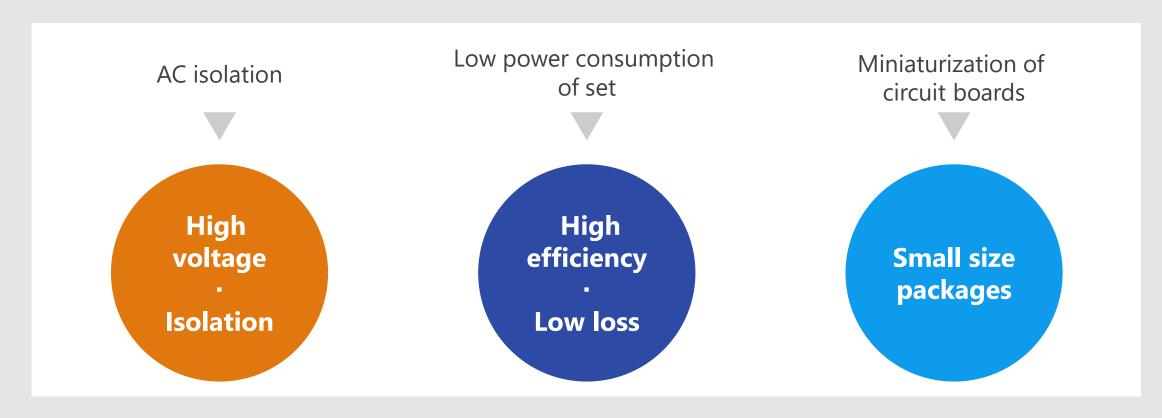


^{*} Click on the blue circled numbers above to view detailed descriptions.



Device solutions to address customer needs

As described above, in the design of Smart Plug, "AC isolation", "Low power consumption of set" and "Miniaturization of circuit boards" are important factors. Toshiba's proposals are based on these three solution perspectives.



Device solutions to address customer needs

	High voltage . Isolation	High efficiency . Low loss	Small size packages
1 TVS diode			
2 Schottky barrier diode			
3 Small signal MOSFET			
4 Photorelay			
5 Photovoltaic output photocoupler			
6 DTMOSIV Series MOSFET			
7 Triac output photocoupler			
8 Small surface mount LDO regulato	r		







Absorbs static electricity (ESD) from external terminals, prevents circuit malfunction and protects devices.

High ESD pulse absorption performance

Improved ESD absorption compared to our conventional products. (50 % reduction in operating resistance) For some products, both low operating resistance and low capacitance are realized and ensures high signal protection performance and signal quality.

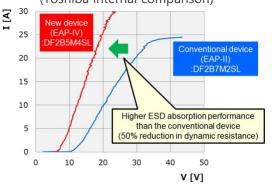
2 Suppress ESD energy by low clamp voltage

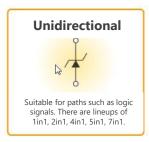
Protect the connected circuits/devices using Toshiba own technology.

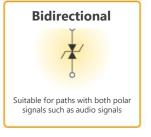
Suitable for high density mounting

A variety of compact packages are available.

ESD pulse absorption performance (Toshiba internal comparison)







Lineup					
Part number	DF2B7ASL	DF2B5M4SL	DF2B6M4SL	DF2B6M4BSL	
Package		SL2	&		
V _{ESD} [kV]	±30	±20	±20	±8	
V _{RWM} (Max) [V]	5.5	3.6	5.5	5.5	
C _t (Typ.) [pF]	8.5	0.2	0.2	0.12	
R _{DYN} (Typ.) [Ω]	0.2	0.5	0.5	1.05	

(Note) This device is for ESD protection only and cannot be used for purposes other than ESD protection.







The schottky barrier diode suitable for small equipment applications.

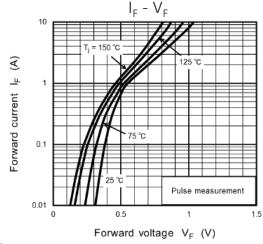
High speed switching

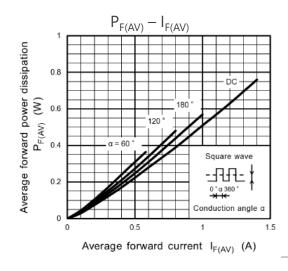
It is suitable for high speed switching applications.

2 Small package

This small package is suitable for high density mounting.

CRS13 Characteristics Curves





Lineup						
Part number	CRS03	CRS13				
Package	S-FLAT™					
V _{RRM} [V]	30	60				
I _{F(AV)} [A]	1.0	1.0				
V _{FM} (Max) [V]	0.45	0.55				
I _{RRM} (Max) [μA]	100	50				







SSM3K36FS

₽

Suitable for power switching and contribute to miniaturization.

Low voltage operation

Operates down to $V_{GS} = 1.5 \text{ V}$

Ip - Vps

Drain-source voltage V_{DS} (V)

Common Source

SSM3K36FS ID – VGS 1000 Ta = 1000 °C Ta = 1000 °C 25 °C Coi

Gate-source voltage VGS (V)

DescriptionLow on-resistance

By reducing on-resistance between the drain and source, heat generation and power consumption can be kept low.

Lineup							
Part number	SSM3K36FS	SSM3K56FS					
Package	SSM	SSM					
V _{DSS} [V]	20	20					
I _D [A]	0.5	0.8					
P _D [W]	0.15	0.15					
$R_{DS(ON)}$ (Max) $[\Omega]$ @ V_{GS} = 4.5 V	0.66	0.235					
Polarity	N-ch	N-ch					







Photorelay consists of an infrared light emitting diode optically coupled to a photo-MOSFET and is suitable for replacing mechanical relays.

Low on-resistance

Maximum on-resistance R_{ON} at turn-on is 2 Ω (at I_{ON} = 0.6 A).

Wide range of ON current

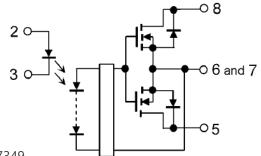
Wide range of allowed ON current I_{ON} , suitable for power line control (maximum 0.6 A : A connected) [Note1]

Yarious lead forming option

Lead forming options (through-hole type and lead forming options. Five total selections) allow design freedom and miniaturization of the set.

[Note1] Please refer to the technical data sheet for connection.

Internal equivalent circuit



UL certified UL1577, File No. E67349

cUL certified CSA Component Acceptance Service No.5A File No. E67349

UL-recognized: UL 508, File No.E499232 [Note2]

VDE-approved: EN 60747-5-5 [Note3]

[Note2] Please refer Absolute Maximum Ratings (UL-recognized UL 508) for UL 508 products.

[Note3] When a VDE approved type is needed, please designate the Option (D4).

Lineup						
Part number	TLP3549					
Package	DIP8					
V _{OFF} [V]	600					
V _{DD} (Max) [V]	480					
I _F (Max) [mA]	25					
I _{ON} (Max) [A]	0.6					
BV _s [Vrms]	2500					

Photovoltaic output photocoupler TLP3906 / TLP3910







Value provided

Photocoupler consists of an infrared light emitting diode optically coupled to a photo-diode array and is suitable for driving gate of MOSFET.

For MOSFET gate driver

Photodiode is connected in series, suitable for driving the gate of MOSFET. No need to use external discharging resistor

1: Anode (Input)

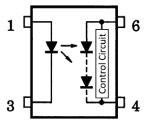
Since the control circuit is on the detector side, there is no need to connect an external discharging resistor.

Improved switching speed

Maximum value of t_{on} and t_{off} are 1 ms and 0.5 ms, respectively. (TLP3910)

Internal equivalent circuit

TLP3906



- 1: Anode (Input)
- 3: Cathode (Input) 4: Cathode (Output) 6: Anode (Output)
- 4: Cathode (Output) 5: Cathode (Output) 6: Anode (Output)

TLP3910

UL certified UL1577, File No.E67349 cUL certified CSA Component Acceptance Service No.5A File No.E67349 VDE certified EN60747-5-5 (TLP3906/TLP3910), EN62368-1 (TLP3906) [Note] [Note] To specify a VDE certified model, request a (V4) model

Lineup

Part number	TLP3906	TLP3910		
Package	4pin SO6	SO6L To		
I _F [mA]	30	30		
V _{OC} (Min) [V]	7	14		
I _{SC} (Min) [μA]	12	12		
BV _s [Vrms]	3750	5000		
Creepage distance (Min) [mm]	5.0	8.0		







30 % reduction in the figure of merit RonA (compared with Toshiba conventional products), improving power supply efficiency and contributing to miniaturization.

RonA 30 % reduction

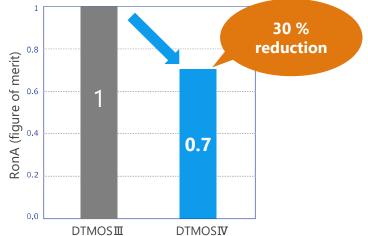
Adoption of newly developed single-epitaxial process to reduce the figure of merit RonA by 30 %. (Compared with DTMOSIII products from Toshiba)

2 Reduction of on-resistance increase at high temperature

The single epitaxial process reduces the on-resistance increase at high temperature.

Optimization of switching speed

Optimization of switching speed has been achieved by reduction of C_{OSS} (by 12 %, compared with Toshiba conventional products) and others.



Lineup							
Part number	TK8P60W	TK16G60W					
Package	DPAK •	D2PAK					
V _{DSS} [V]	600	600					
I _D [A]	8.0	15.8					
P _D [W]	80	130					
C _{iss} (Typ.) [pF]	570	1350					
$R_{DS(ON)}$ (Max) [Ω]	0.5	0.19					
Polarity	N-ch	N-ch					

◆ Return to Block Diagram TOP

[Note] Compared with Toshiba conventional products







Photocoupler suitable for AC switching.

Small package (4pin SO6)

Thin 4pin SO6 (3.7 x 7.0 x 2.1 mm) package allows high density mounting.

High isolation voltage (3750 Vrms)

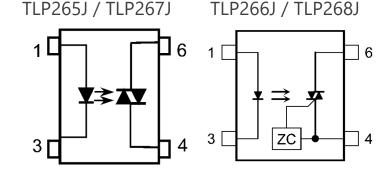
Isolation voltage is 3750 Vrms. Insulator thickness is 0.4 mm, creepage and clearance distances are 5.0 mm. Compliant with reinforced insulation safety standards.

Compatible with zero-cross output

Maximum output current is 70 mA.

Higher output is possible using main triac connection. Zero-cross (ZC) compatible output is also available.

Pin layout



- 1. Anode
- 3. Cathode
- 4. Triac pin
- 6. Triac pin

Lineup								
Part number	TLP265J	TLP266J	TLP267J	TLP268J				
Package	4pin SO6							
Output Type	Non-ZC	ZC	Non-ZC	ZC				
V _{DRM} [V]	600							
I _{FT} (Max) [mA]	10 3							
I _{T(RMS)} [mA]	70							
BV _s [Vrms] 3750								







Wide lineup from general purpose type to small package type are provided. Contribute to realize a stable power supply not affected by fluctuation of battery.

Low dropout voltage

The originally developed latest process significantly improved the dropout voltage characteristics.

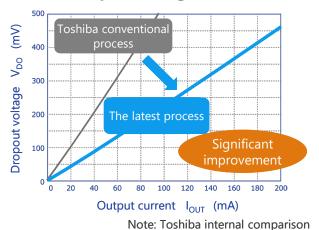
High PSRR Low output noise voltage

Many product series that realize both high PSRR (Power Supply Rejection Ratio) and low output noise voltage characteristics are provided. They are suitable for stable power supply for analog circuit.

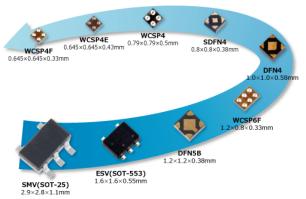
3 Low current consumption

 $0.34~\mu A$ of $I_{B(ON)}$ is realized by utilizing CMOS process and unique circuit technology. (TCR3U Series)

Low dropout voltage



Rich package lineup



Lineup									
Part number	TCR15AG Series	TCR13AG Series	TCR8BM Series	TCR5BM Series	TCR5RG Series	TCR3RM Series	TCR3U Series	TCR2L Series	TAR5 Series
Features	High PSRR			Low Low c			urrent mption	15 V Input voltage Bipolar type	
I _{OUT} (Max) [A]				.5	0.	.3		0.2	
PSRR (Typ.) [dB] @f = 1 kHz	95	90	98	98	100	100	70	-	70
I _B (Typ.) [μΑ]	25	56	20	19	7	7	0.34	1	170

If you are interested in these products and have questions or comments about any of them, please do not hesitate to contact us below:

Contact address: https://toshiba.semicon-storage.com/ap-en/contact.html

Terms of use

These terms of use are made between Toshiba Electronic Devices and Storage Corporation ("We") and customers who use documents and data that are consulted to design electronics applications on which our semiconductor devices are mounted ("this Reference Design"). Customers shall comply with these terms of use. Please note that it is assumed that customers agree to any and all of the terms of use if customers download this Reference Design. We may, at our sole and exclusive discretion, change, alter, modify, add, and/or remove any part of these terms of use at any time without any prior notice. We may terminate these terms of use at any time and for any reason. Upon termination of these terms of use, customers shall destroy this Reference Design. In the event of any breach thereof by customers, customers shall destroy this Reference Design, and furnish us a written confirmation to prove such destruction.

1. Restrictions on usage

- 1. This Reference Design is provided solely as reference data for designing electronics applications. Customers shall not use this Reference Design for any other purpose, including without limitation, verification of reliability.
- 2.This Reference Design is for customer's own use and not for sale, lease or other transfer.
- 3.Customers shall not use this Reference Design for evaluation in high or low temperature, high humidity, or high electromagnetic environments.
- 4. This Reference Design shall not be used for or be incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable laws or regulations.

2. Limitations

- 1.We reserve the right to make changes to this Reference Design without notice.
- 2. This Reference Design should be treated as a reference only. We are not responsible for any incorrect or incomplete data and information.
- 3.Semiconductor devices can malfunction or fail. When designing electronics applications by referring to this Reference Design, customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of semiconductor devices could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Customers must also refer to and comply with the latest versions of all relevant our information, including without limitation, specifications, data sheets and application notes for semiconductor devices, as well as the precautions and conditions set forth in the "Semiconductor Reliability Handbook".
- 4. When designing electronics applications by referring to this Reference Design, customers must evaluate the whole system adequately. Customers are solely responsible for all aspects of their own product design or applications. WE ASSUME NO LIABILITY FOR CUSTOMERS' PRODUCT DESIGN OR APPLICATIONS.
- 5.No responsibility is assumed by us for any infringement of patents or any other intellectual property rights of third parties that may result from the use of this Reference Design. No license to any intellectual property right is granted by this terms of use, whether express or implied, by estoppel or otherwise.
- 6.THIS REFERENCE DÉSIĞN IS PROVIDED "AS IS". WE (a) ASSUME NO L'IABILITY WHATSOÉVER, INCLUDING WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR LOSS, INCLUDING WITHOUT LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND LOSS OF DATA, AND (b) DISCLAIM ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO THIS REFERENCE DESIGN, INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, ACCURACY OF INFORMATION, OR NONINFRINGEMENT.

3. Export Control

Customers shall not use or otherwise make available this Reference Design for any military purposes, including without limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile technology products (weapons of mass destruction). This Reference Design may be controlled under the applicable export laws and regulations including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the U.S. Export Administration Regulations. Export and re-export of this Reference Design are strictly prohibited except in compliance with all applicable export laws and regulations.

4. Governing Laws

These terms of use shall be governed and construed by the laws of Japan.

RESTRICTIONS ON PRODUCT USE

- Toshiba Electronic Devices & Storage Corporation, and its subsidiaries and affiliates (collectively "TOSHIBA"), reserve the right to make changes to the information in this document, and related hardware, software and systems (collectively "Product") without notice.
- This document and any information herein may not be reproduced without prior written permission from TOSHIBA. Even with TOSHIBA's written permission, reproduction is permissible only if reproduction is without alteration/omission.
- Though TOSHIBA works continually to improve Product's quality and reliability, Product can malfunction or fail. Customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of Product could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Before customers use the Product, create designs including the Product, or incorporate the Product into their own applications, customers must also refer to and comply with (a) the latest versions of all relevant TOSHIBA information, including without limitation, this document, the specifications, the data sheets and application notes for Product and the precautions and conditions set forth in the "TOSHIBA Semiconductor Reliability Handbook" and (b) the instructions for the application with which the Product will be used with or for. Customers are solely responsible for all aspects of their own product design or applications, including but not limited to (a) determining the appropriateness of the use of this Product in such design or applications; (b) evaluating and determining the applicability of any information contained in this document, or in charts, diagrams, programs, algorithms, sample application circuits, or any other referenced documents; and (c) validating all operating parameters for such designs and applications. **TOSHIBA ASSUMES NO LIABILITY FOR CUSTOMERS' PRODUCT DESIGN OR APPLICATIONS.**
- PRODUCT IS NEITHER INTENDED NOR WARRANTED FOR USE IN EQUIPMENTS OR SYSTEMS THAT REQUIRE EXTRAORDINARILY HIGH LEVELS OF QUALITY AND/OR RELIABILITY, AND/OR A MALFUNCTION OR FAILURE OF WHICH MAY CAUSE LOSS OF HUMAN LIFE, BODILY INJURY, SERIOUS PROPERTY DAMAGE AND/OR SERIOUS PUBLIC IMPACT ("UNINTENDED USE"). Except for specific applications as expressly stated in this document, Unintended Use includes, without limitation, equipment used in nuclear facilities, equipment used in the aerospace industry, lifesaving and/or life supporting medical equipment, equipment used for automobiles, trains, ships and other transportation, traffic signaling equipment, equipment used to control combustions or explosions, safety devices, elevators and escalators, and devices related to power plant. IF YOU USE PRODUCT FOR UNINTENDED USE, TOSHIBA ASSUMES NO LIABILITY FOR PRODUCT. For details, please contact your TOSHIBA sales representative or contact us via our website.
- Do not disassemble, analyze, reverse-engineer, alter, modify, translate or copy Product, whether in whole or in part.
- Product shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable laws or regulations.
- The information contained herein is presented only as guidance for Product use. No responsibility is assumed by TOSHIBA for any infringement of patents or any other intellectual property rights of third parties that may result from the use of Product. No license to any intellectual property right is granted by this document, whether express or implied, by estoppel or otherwise.
- ABSENT A WRITTEN SIGNED AGREEMENT, EXCEPT AS PROVIDED IN THE RELEVANT TERMS AND CONDITIONS OF SALE FOR PRODUCT, AND TO THE MAXIMUM EXTENT ALLOWABLE BY LAW, TOSHIBA (1) ASSUMES NO LIABILITY WHATSOEVER, INCLUDING WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR LOSS, INCLUDING WITHOUT LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND LOSS OF DATA, AND (2) DISCLAIMS ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO SALE, USE OF PRODUCT, OR INFORMATION, INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, ACCURACY OF INFORMATION, OR NONINFRINGEMENT.
- Product may include products using GaAs (Gallium Arsenide). GaAs is harmful to humans if consumed or absorbed, whether in the form of dust or vapor. Handle with care and do not break, cut, crush, grind, dissolve chemically or otherwise expose GaAs in Product.
- Do not use or otherwise make available Product or related software or technology for any military purposes, including without limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile technology products (mass destruction weapons). Product and related software and technology may be controlled under the applicable export laws and regulations including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the U.S. Export Administration Regulations. Export and re-export of Product or related software or technology are strictly prohibited except in compliance with all applicable export laws and regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. Please use Product in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. **TOSHIBA ASSUMES NO LIABILITY FOR DAMAGES OR LOSSES OCCURRING AS A RESULT OF NONCOMPLIANCE WITH APPLICABLE LAWS AND REGULATIONS.**

TOSHIBA

^{*} S-FLAT™ is a trademark of Toshiba Electronic Devices & Storage Corporation.

^{*} All other company names, product names, and service names may be trademarks of their respective companies.